



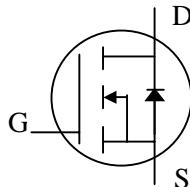
N-channel Enhancement-mode Power MOSFET

Simple Drive Requirement

Repetitive Avalanche Rated

Fast Switching Speed

RoHS-compliant, halogen-free

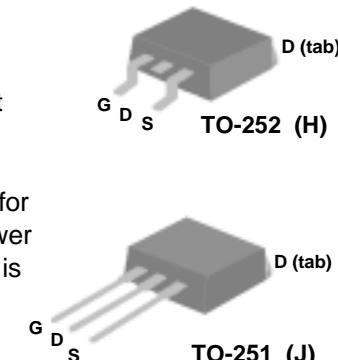


BV_{DSS}	700V
$R_{DS(ON)}$	4.4Ω
I_D	2.5A

Description

Advanced Power MOSFETs from APEC provide the designer with the best combination of fast switching, low on-resistance and cost-effectiveness.

The AP03N70H-H-HF-3 is in the TO-252 package which is widely preferred for commercial and industrial surface mount applications such as medium-power AC/DC converters. The through-hole TO-251 version (AP03N70J-H-HF-3) is available where a small PCB footprint or attached heatsink is required.



Absolute Maximum Ratings

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	700	V
V_{GS}	Gate-Source Voltage	±30	V
I_D at $T_C=25^\circ\text{C}$	Continuous Drain Current ³	2.5	A
I_D at $T_C=100^\circ\text{C}$	Continuous Drain Current ³	1.6	A
I_{DM}	Pulsed Drain Current ¹	8	A
P_D at $T_C=25^\circ\text{C}$	Total Power Dissipation	54	W
	Linear Derating Factor	0.44	W/°C
E_{AS}	Single Pulse Avalanche Energy ²	31	mJ
I_{AR}	Avalanche Current	2.5	A
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Operating Junction Temperature Range	-55 to 150	°C

Thermal Data

Symbol	Parameter	Value	Unit
R_{thj-a}	Maximum Thermal Resistance, Junction-case	2.3	°C/W
R_{thj-c}	Maximum Thermal Resistance, Junction-ambient	110	°C/W

Ordering Information

AP03N70H-H-HF-3TR : in RoHS-compliant halogen-free TO-252 shipped on tape and reel (3000 pcs/reel)

AP03N70J-H-HF-3TB : in RoHS-compliant halogen-free TO-251 shipped in tubes (80pcs/tube)



Electrical Specifications at $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{\text{GS}}=0\text{V}$, $I_{\text{D}}=1\text{mA}$	700	-	-	V
$\Delta \text{BV}_{\text{DSS}}/\Delta T_j$	Breakdown Voltage Temperature Coefficient	Reference to 25°C , $I_{\text{D}}=1\text{mA}$	-	0.6	-	$\text{V}/^\circ\text{C}$
$R_{\text{DS}(\text{ON})}$	Static Drain-Source On-Resistance	$V_{\text{GS}}=10\text{V}$, $I_{\text{D}}=1.6\text{A}$	-	-	4.4	Ω
$V_{\text{GS}(\text{th})}$	Gate Threshold Voltage	$V_{\text{DS}}=V_{\text{GS}}$, $I_{\text{D}}=250\mu\text{A}$	2	-	4	V
g_{fs}	Forward Transconductance	$V_{\text{DS}}=10\text{V}$, $I_{\text{D}}=1.6\text{A}$	-	2	-	S
I_{DSS}	Drain-Source Leakage Current ($T_j=25^\circ\text{C}$)	$V_{\text{DS}}=600\text{V}$, $V_{\text{GS}}=0\text{V}$	-	-	10	μA
	Drain-Source Leakage Current ($T_j=150^\circ\text{C}$)	$V_{\text{DS}}=480\text{V}$, $V_{\text{GS}}=0\text{V}$	-	-	100	μA
I_{GSS}	Gate-Source Leakage	$V_{\text{GS}}=\pm 30\text{V}$	-	-	± 100	nA
Q_g	Total Gate Charge ³	$I_{\text{D}}=1\text{A}$	-	12	20	nC
Q_{gs}	Gate-Source Charge	$V_{\text{DS}}=480\text{V}$	-	3	-	nC
Q_{gd}	Gate-Drain ("Miller") Charge	$V_{\text{GS}}=10\text{V}$	-	4	-	nC
$t_{\text{d}(\text{on})}$	Turn-on Delay Time ³	$V_{\text{DD}}=300\text{V}$	-	8.5	-	ns
t_r	Rise Time	$I_{\text{D}}=2.5\text{A}$	-	6	-	ns
$t_{\text{d}(\text{off})}$	Turn-off Delay Time	$R_{\text{G}}=10\Omega$, $V_{\text{GS}}=10\text{V}$	-	19	-	ns
t_f	Fall Time	$R_{\text{D}}=120\Omega$	-	8	-	ns
C_{iss}	Input Capacitance	$V_{\text{GS}}=0\text{V}$	-	590	950	pF
C_{oss}	Output Capacitance	$V_{\text{DS}}=25\text{V}$	-	50	-	pF
C_{rss}	Reverse Transfer Capacitance	f=1.0MHz	-	6	-	pF
R_g	Gate Resistance	f=1.0MHz	-	3.4	5.1	Ω

Source-Drain Diode

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
V_{SD}	Forward On Voltage ³	$I_{\text{S}}=2.5\text{A}$, $V_{\text{GS}}=0\text{V}$	-	-	1.5	V
t_{rr}	Reverse Recovery Time ²	$I_{\text{S}}=2.5\text{A}$, $V_{\text{GS}}=0\text{V}$	-	407	-	ns
Q_{rr}	Reverse Recovery Charge	$dI/dt=100\text{A}/\mu\text{s}$	-	2110	-	nC

Notes:

- 1.Pulse width limited by safe operating area
- 2.Starting $T_j=25^\circ\text{C}$, $V_{\text{DD}}=50\text{V}$, $L=10\text{mH}$, $R_{\text{G}}=25\Omega$, $I_{\text{AS}}=2.5\text{A}$.
- 3.Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

APEC DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

APEC RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN.



Typical Electrical Characteristics

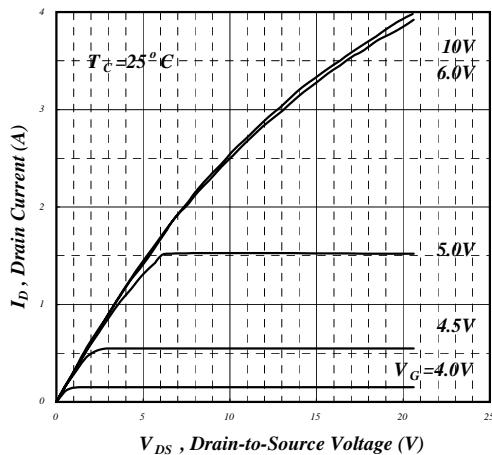


Fig 1. Typical Output Characteristics

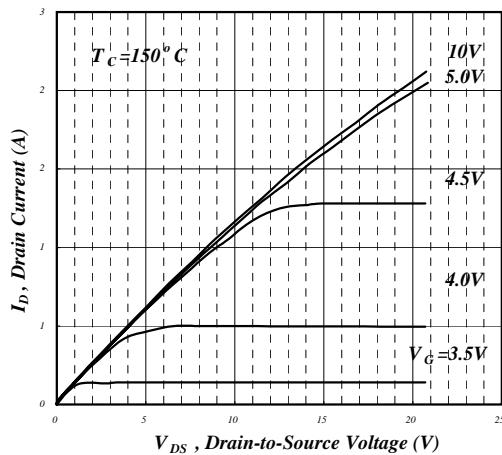


Fig 2. Typical Output Characteristics

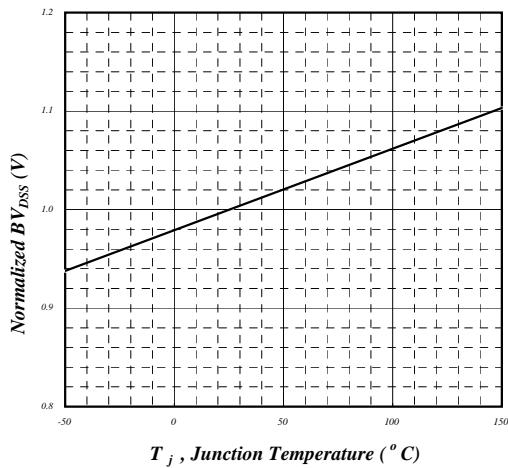


Fig 3. Normalized BV_{DSS}
vs. Junction Temperature

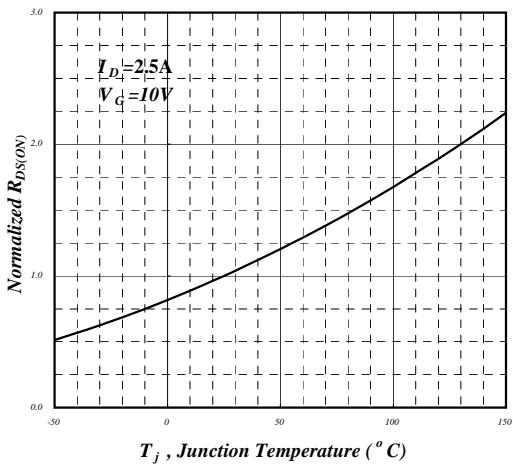


Fig 4. Normalized On-Resistance
vs. Junction Temperature

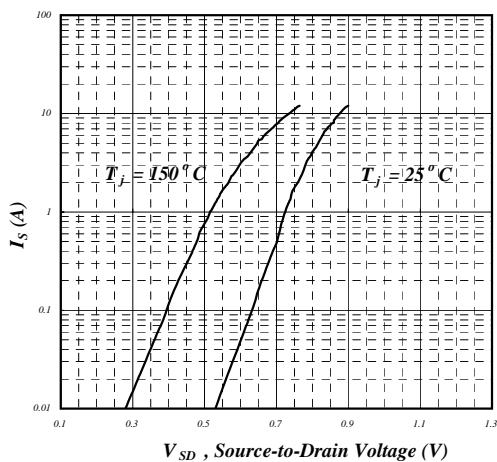


Fig 5. Forward Characteristic of
Reverse Diode

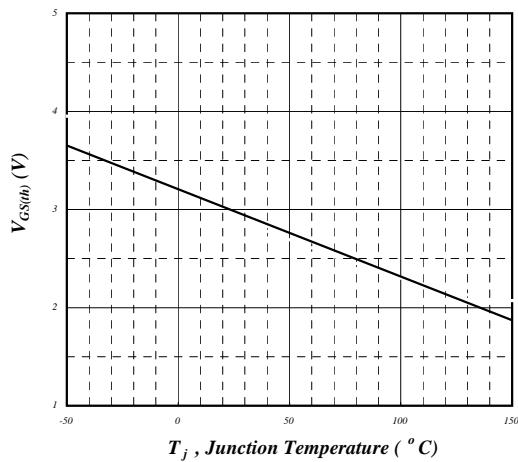


Fig 6. Gate Threshold Voltage vs.
Junction Temperature



Typical Electrical Characteristics (cont.)

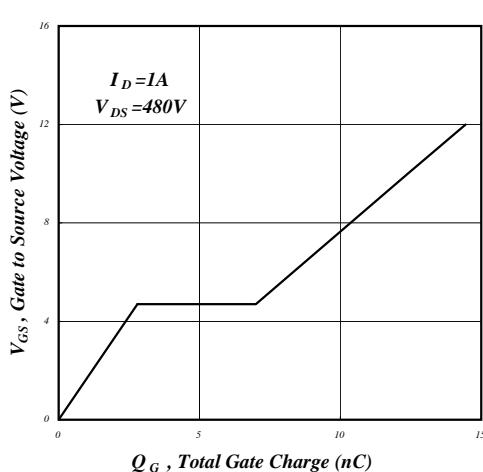


Fig 7. Gate Charge Characteristics

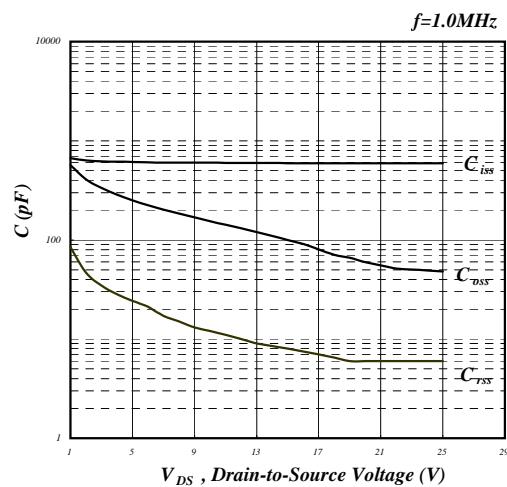


Fig 8. Typical Capacitance Characteristics

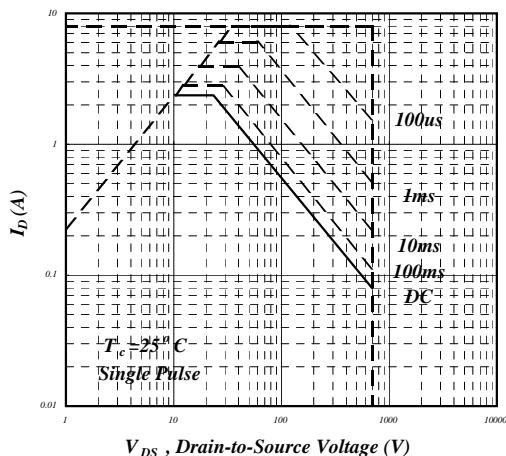


Fig 9. Maximum Safe Operating Area

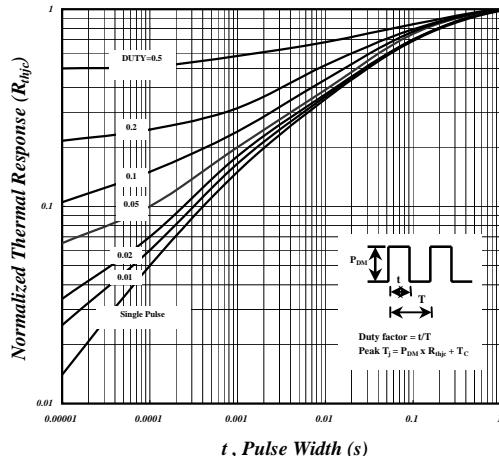


Fig 10. Effective Transient Thermal Impedance

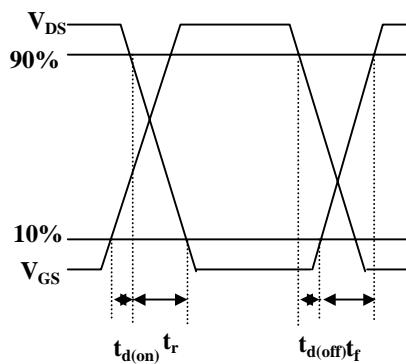


Fig 11. Switching Time Waveforms

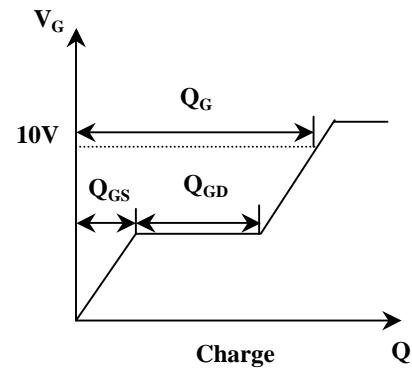
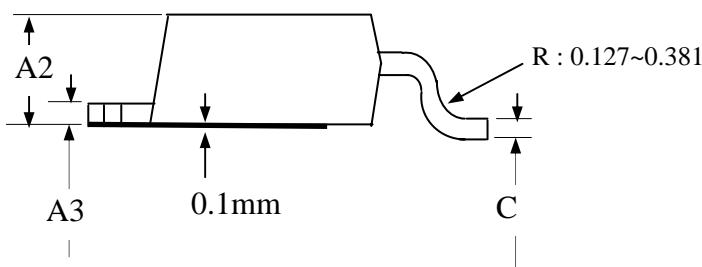
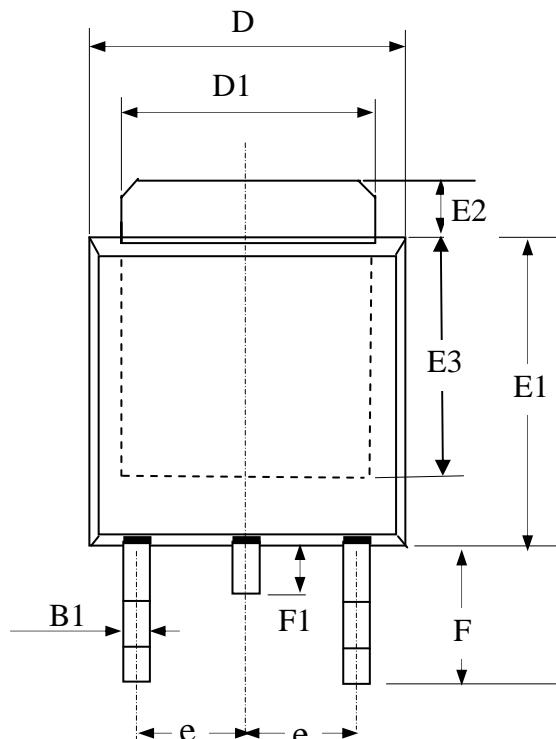


Fig 12. Gate Charge Waveform



Package Dimensions: TO-252

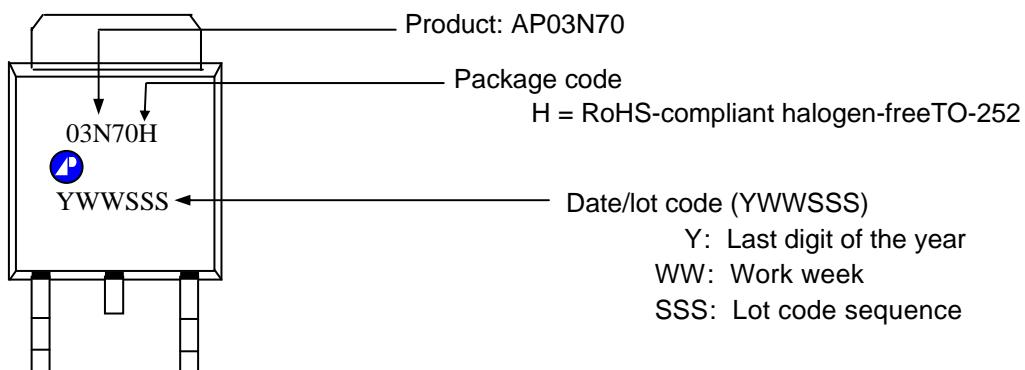


SYMBOLS	Millimeters		
	MIN	NOM	MAX
A2	1.80	2.30	2.80
A3	0.40	0.50	0.60
B1	0.40	0.70	1.00
D	6.00	6.50	7.00
D1	4.80	5.35	5.90
E3	3.50	4.00	4.50
F	2.20	2.63	3.05
F1	0.50	0.85	1.20
E1	5.10	5.70	6.30
E2	0.50	1.10	1.80
e	--	2.30	--
C	0.35	0.50	0.65

1. All dimensions are in millimeters.

2. Dimensions do not include mold protrusions.

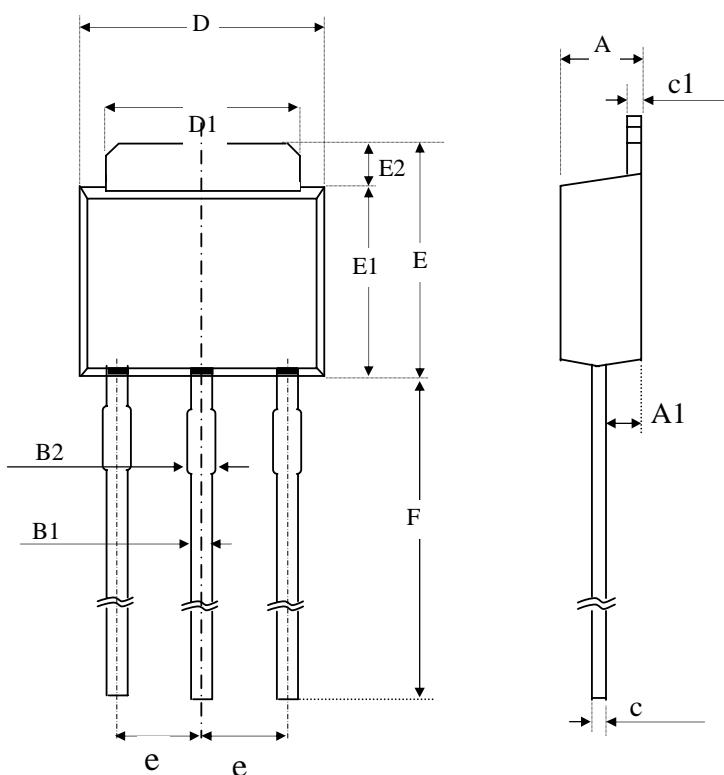
Marking Information: TO-252



Packing: Parts are shipped on tape and reel, 3000pcs per reel. The reel is sealed in a moisture barrier bag (MBB). Once the bag is opened, the parts should be considered moisture-sensitive, as defined in IPC/JEDEC standard, J-STD-020C, with MSL=3, and handled accordingly.



Package Dimensions: TO-251



SYMBOLS	Millimeters		
	MIN	NOM	MAX
A	2.20	2.30	2.40
A1	0.90	1.20	1.50
B1	0.40	0.60	0.80
B2	0.60	0.85	1.05
c	0.40	0.50	0.60
c1	0.40	0.50	0.60
D	6.40	6.60	6.80
D1	4.80	5.20	5.50
E	6.70	7.00	7.30
E1	5.40	5.60	5.80
E2	1.30	1.50	1.70
e	----	2.30	----
F	7.00	8.30	9.60

1. All dimensions are in millimeters.

2. Dimensions do not include mold protrusions.

Marking Information: TO-251

